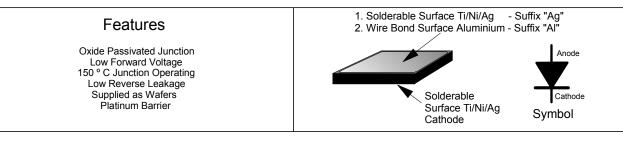




SB073P125-W-Ag/Al Schottky Barrier Diode Wafer 73 Mils, 125 Volt, 5 Amp

Data Sheet



Electrical Characteristics @ 25°c	Symbol	Unit	SB073P125-W-Ag/AI (See <u>ordering code</u> below)
Maximum Repetitive Reverse Voltage (2)	V _{RRM}	Volt	125
Maximum Forward Voltage (1)(2)	V _F	Volt	0.78
Typical Average Forward Rectified Current (2)	I _{F(AV)}	Amp	5
Reverse Leakage Current (2)	I _R	μA	10
Reverse Leakage Current @ 125°C (2)	I _R	mA	5
Junction Operating Temperature Range (2)	TJ	°C	-65 to +150
Storage Temperature Range (2)	T _{SG}	°C	-65 to +150

(1) Pulse Width tp = $< 300\mu$ S, Duty Cycle < 2%

(2) The characteristics above assume the die are assembled in indusry standard packages using appropriate attach methods.

